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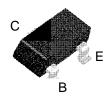
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## **FSB649**



## SuperSOT<sup>™</sup>-3

## **NPN Low Saturation Transistor**

These devices are designed with high current gain and low saturation voltage with collector currents up to 3A continuous. Sourced from Process NC.

## **Absolute Maximum Ratings\*** T<sub>A = 25°C unless otherwise noted</sub>

Symbol	Parameter	FSB649	Units
VCEO	Collector-Emitter Voltage	25	V
V <sub>CBO</sub>	Collector-Base Voltage	35	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current - Continuous	3	Α
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1) These ratings are based on a maximum junction temperature of 150°C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### 

Symbol	Characteristic	Max	Units
		FSB649	
P <sub>D</sub>	Total Device Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	250	°C/W

## NPN Low Saturation Transistor

(continued)

## **Electrical Characteristics**

T<sub>A = 25°C</sub> unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAI	RACTERISTICS				
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10 mA	25		V
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 100 μA	35		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 100 μA	5		V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 30 V		100	nA
		$V_{CB} = 30 \text{ V}, T_A = 100^{\circ}\text{C}$		10	uA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4V		100	nA
ON CHAR	ACTERISTICS*			1	<u> </u>
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 50 mA, V <sub>CE</sub> = 2 V	70		-
		$I_C = 1 A$ , $V_{CE} = 2 V$	100	300	
		$I_C = 2 A$ , $V_{CE} = 2 V$	75		
		$I_C = 6 A$ , $V_{CE} = 2 V$	15		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA		300	mV
2 = (32)		$I_C = 3 \text{ A}, I_B = 300 \text{ mA}$		600	
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA		1.25	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1 A, V <sub>CE</sub> = 2 V		1	V
SMALL SI	GNAL CHARACTERISTICS			•	•
C <sub>obo</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1MHz		50	pF
f <sub>T</sub>	Transition Frequency	$I_C = 100 \text{ mA}, V_{CE} = 5 \text{ V}, f=100 \text{MHz}$	150		-

<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

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Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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